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(54) **COT TYPE LIQUID CRYSTAL DISPLAY
DEVICE**

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G02F 1/1362 (2006.01)

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G02F 2201/48 (2013.01)

(58) **Field of Classification Search**

USPC 349/106, 110, 155, 156
See application file for complete search history.

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Primary Examiner — Edward Glick

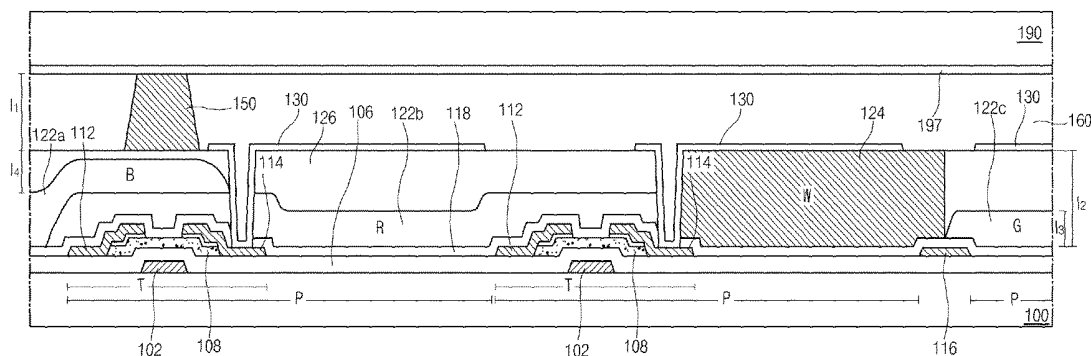
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(57) **ABSTRACT**

Disclosed is a color filter on transistor (COT) type liquid crystal display device that may include red, green, blue and white pixels on a substrate; red, green and blue color filters in the red green and blue pixels, respectively, and a white pattern in the white pixel; a planarization layer on the red, green and blue color filters; and a column spacer on the planarization layer, wherein the column spacer and the white pattern are made of the substantially same material.

12 Claims, 8 Drawing Sheets



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FIG. 1

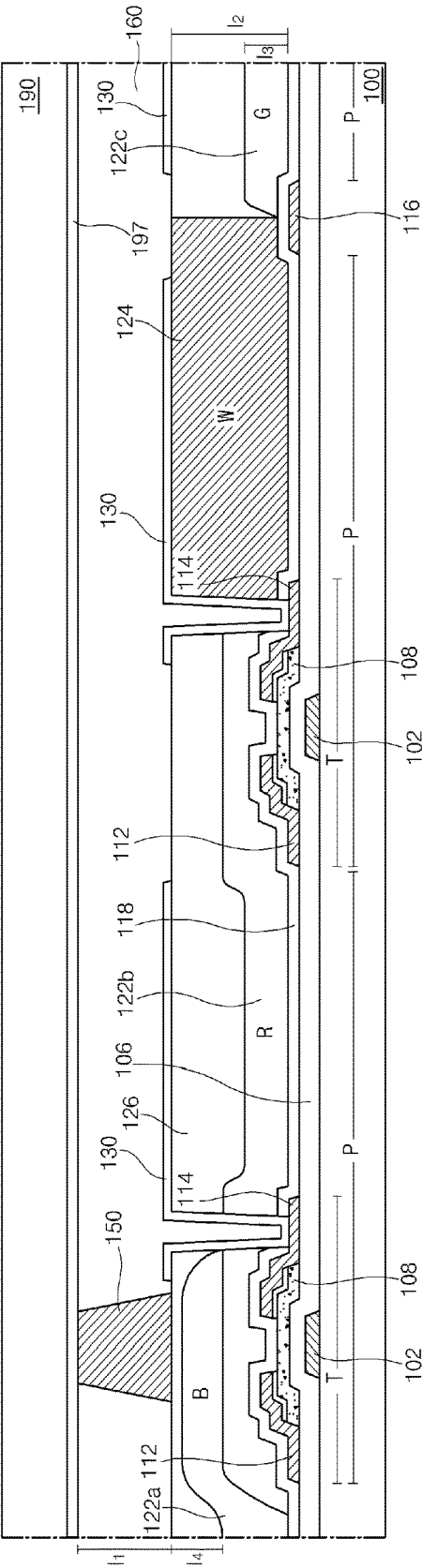


FIG. 2A

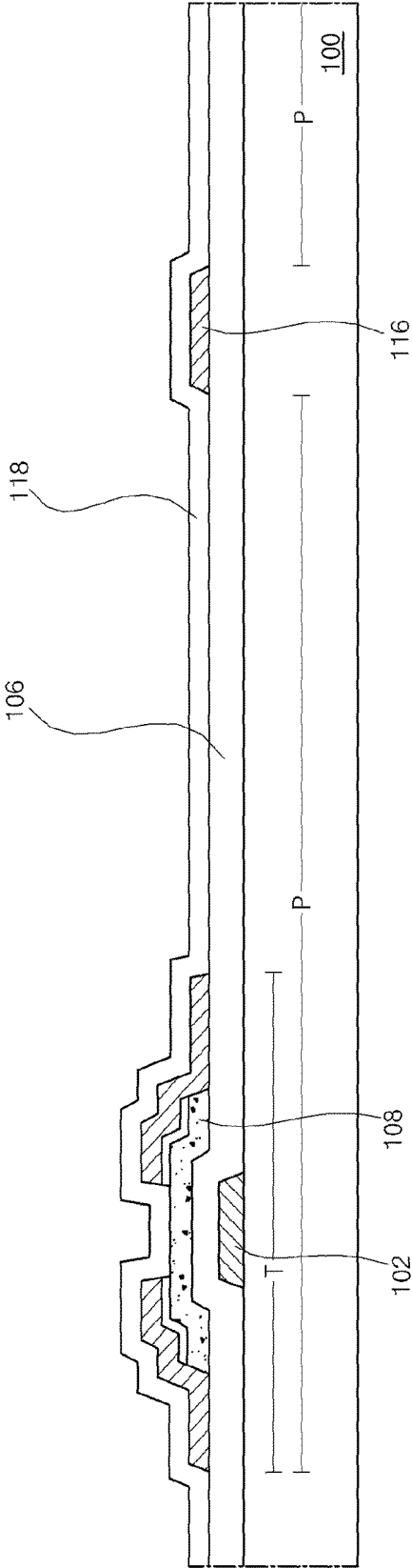


FIG. 2B

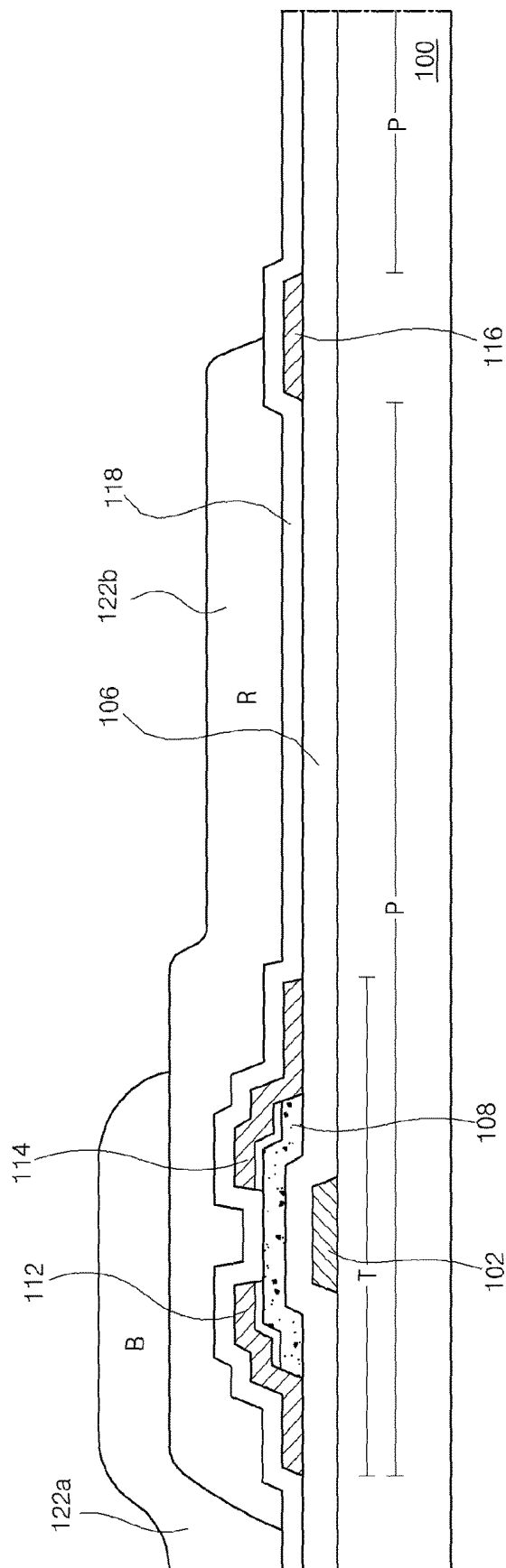


FIG. 2D

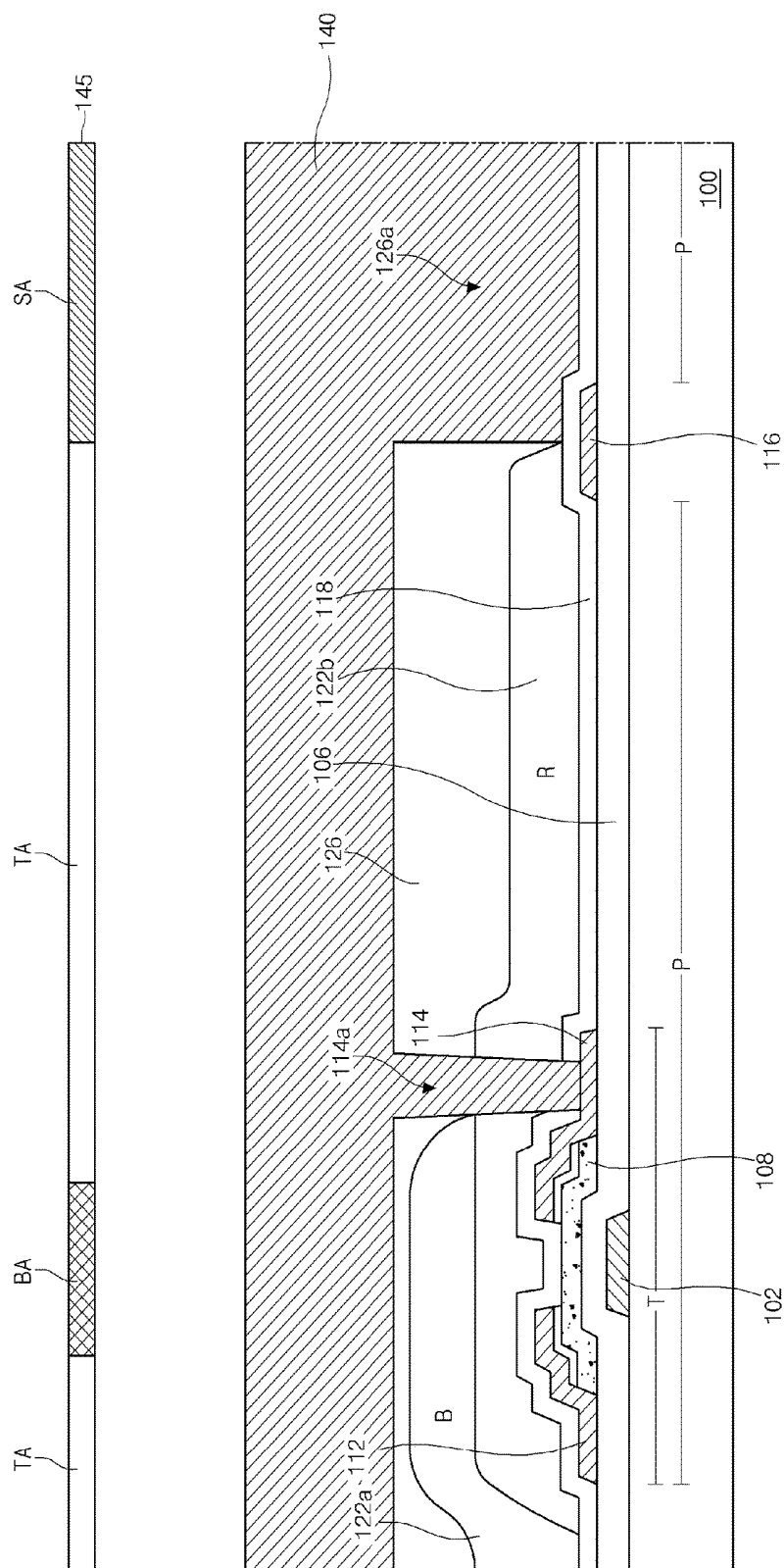
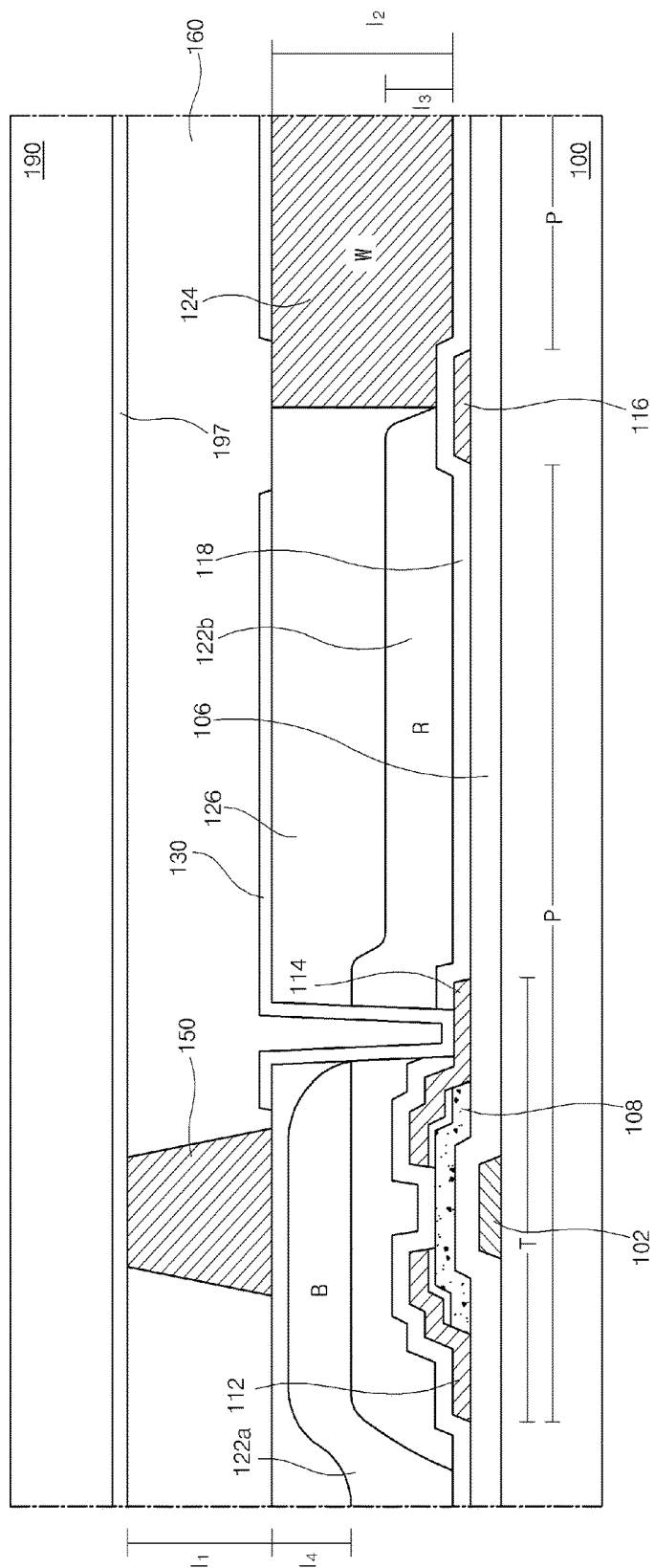


FIG. 2G



COT TYPE LIQUID CRYSTAL DISPLAY DEVICE

This application claims the benefit of Korean Patent Application No. 10-2013-0168767, filed on Dec. 31, 2013, which is hereby incorporated by reference for all purposes as if fully set forth herein.

BACKGROUND OF THE INVENTION

Field of the Disclosure

The present invention relates to a liquid crystal display device (LCD), and more particularly, to a color filter on transistor (COT) type LCD and method of manufacturing the same.

Discussion of the Related Art

Liquid crystal display devices (LCDs), which are advantageous in displaying moving images, have high contrast ratio and thus have been actively used for TVs or monitors. LCDs display images using optical anisotropy and polarization of liquid crystal.

An LCD uses a liquid crystal panel as a main component, which includes upper and lower substrates facing each other with a liquid crystal layer therebetween. Difference in transmittance is realized by changing alignment direction of liquid crystal molecules according to an electric field induced in the liquid crystal panel.

Recently, a color filter on transistor (COT) type LCD, which has both thin film transistors (TFTs) and color filters on the same substrate, has been used due to its advantage of reducing an alignment margin of the upper and lower substrates, which can thus increase the aperture ratio.

A COT-type LCD according to the related art includes a first substrate on which TFTs, color filters, pixel electrodes and a first alignment layer are formed, a second substrate coupled to the first substrate using a sealant on which common electrodes and a second alignment layer are formed, a liquid crystal layer between the first and second substrates, and black column spacers for maintaining a gap between the first and second substrates.

The COT-type LCD may include four color filters i.e., red, green, blue and white color filters in order to increase transmittance.

However, because the COT-type LCD has the white color filter, the number of mask processes to manufacture the COT-type LCD increases. Accordingly, the number of production processes increases, production cost increases, and thus productivity is reduced. Further, there is a problem in that the black resin used for the black column spacer is expensive.

SUMMARY OF THE INVENTION

Accordingly, the present invention is directed to a color filter on transistor (COT) type liquid crystal display device (LCD) and method of manufacturing the same that substantially obviates one or more of the problems due to limitations and disadvantages of the related art.

An advantage of the present invention is to provide a COT-type LCD that can reduce production cost and improve productivity.

Additional features and advantages of the invention will be set forth in the description which follows, and in part will be apparent from the description, or may be learned by practice of the invention. These and other advantages of the invention will be realized and attained by the structure

particularly pointed out in the written description and claims hereof as well as the appended drawings.

To achieve these and other advantages and in accordance with the purpose of the present invention, as embodied and broadly described herein, a color filter on transistor (COT) type liquid crystal display device may, for example, include red, green, blue and white pixels on a substrate; red, green and blue color filters in the red green and blue pixels, respectively, and a white pattern in the white pixel; a planarization layer on the red, green and blue color filters; and a column spacer on the planarization layer, wherein the column spacer and the white pattern are made of the substantially same material.

In another aspect, a method of manufacturing a color filter on transistor (COT) type liquid crystal display device may, for example, include forming a thin film transistor on a first substrate, the thin film transistor including a gate electrode, an active layer and source and drain electrodes; forming a passivation layer on the thin film transistor; forming red, green and blue color filters on the passivation layer in respective pixel regions; forming a planarization layer on the red, green and blue color filters; forming a white pattern hole in the planarization layer; coating an organic material over the substrate having the planarization layer including the white pattern hole; forming a column spacer and a white pattern by patterning the organic material; and forming a pixel electrode electrically connected to the drain electrode.

It is to be understood that both the foregoing general description and the following detailed description are exemplary and explanatory and are intended to provide further explanation of the invention as claimed.

BRIEF DESCRIPTION OF THE DRAWINGS

The accompanying drawings, which are included to provide a further understanding of the invention and are incorporated in and constitute a part of this specification, illustrate embodiments of the invention and together with the description serve to explain the principles of the invention. In the drawings:

FIG. 1 is a cross-sectional view illustrating a color filter on transistor (COT) type liquid crystal display device (LCD) according to an embodiment of the present invention; and

FIGS. 2A to 2G are cross-sectional views illustrating a method of manufacturing a COT-type LCD according to an embodiment of the present invention.

DETAILED DESCRIPTION OF THE ILLUSTRATED EMBODIMENTS

Reference will now be made in detail to embodiments of the present invention, examples of which are illustrated in the accompanying drawings. The same reference numbers may be used throughout the drawings to refer to the same or like parts.

FIG. 1 is a cross-sectional view illustrating a color filter on transistor (COT) type liquid crystal display device (LCD) according to an embodiment of the present invention.

Referring to FIG. 1, the COT-type LCD includes a first substrate **100** on which a TFT **T** and a color filter layer on the TFT are formed, a second substrate **190** on which a common electrode **197** is formed, and a liquid crystal layer **160** between the first and second substrates **100** and **190**.

A plurality of gate lines (not shown) and a plurality of data lines **116** are formed to define a plurality of pixel regions **P** on an inner surface of the first substrate **100**, and the TFT **T** is formed near the crossing portion of the gate line and the

data line **116**. The TFT T includes a gate electrode **102**, a semiconductor layer **108**, and source and drain electrodes **112** and **114**.

A gate insulating layer **106** is formed on the gate electrode **102** and the gate line. A passivation layer **118** is formed on the TFT T to protect the TFT T.

Color filter patterns are formed in the respective pixel regions P. In other words, blue (B), red (R), green (G) and white (W) color filter patterns **122a**, **122b**, **122c** and **124** are formed in the respective pixel regions P. The white color filter pattern **124** is referred to as a white pattern.

The white pattern **124** may be formed at the same layer as the blue, red and green color filter patterns **122a**, **122b** and **122c**. The white pattern **124**, which emits a white light, is used to improve the transmittance of the COT-type LCD.

The blue, red and green color filter patterns **122a**, **122b**, **122c** and the white pattern **124** may be arranged in a stripe type along a column direction.

At least two color filter patterns are stacked on the TFT T to shield the semiconductor layer **108** from light. In other words, the at least two color filter patterns on the TFT T function as a black matrix to reduce or prevent degradation of the TFT T due to the light entering the semiconductor layer **108**.

A planarization layer **126** is formed on the blue, red and green color filter patterns **122a**, **122b** and **122c** to planarize surfaces over the blue, red and green color filter patterns **122a**, **122b** and **122c**.

A pixel electrode **130** is formed on the planarization layer **126** or the white pattern **124** in each pixel region P and is electrically connected to the drain electrode **114**.

The white pattern **124** has its top surface at substantially the same level as a top surface of the planarization layer **126**. In other words, the white pattern **124** and the planarization layer **126** have the substantially same height from the first substrate **100**.

A column spacer **150** is formed over the TFT T to maintain a cell gap between the first and second substrates **100** and **190**.

The column spacer **150** may be formed of the same material as the white pattern **124**, and in the same process of forming the white pattern **124**. For example, the column spacer **150** and the white pattern **124** may be made of an organic material including acrylic resin that is transparent.

Because the column spacer **150** and the white pattern **124** are formed in the same process, a number of mask processes can be reduced in manufacturing a COT-type LCD according to an embodiment of the present invention.

The column spacer **150** and the white pattern **124** may be photosensitive, and they can be patterned through light exposure.

The column spacer **150** has a first thickness **11** to maintain a cell gap between the first and second substrates **100** and **190**. The first thickness **11** may be about 3 μm or less, for example, 2.4 μm .

The white pattern **124** has a second thickness **12**, which is substantially equal to a total thickness of the planarization layer **126** and the blue, red or green color filter **122a**, **122b** or **122c** below the planarization layer **126**, to maintain the cell gap. The second thickness **12** may be about 4 μm or less, for example, 3.7 μm .

Each of the blue, red and green color filters **122a**, **122b** and **122c** in the respective pixel regions P may have a third thickness **13** of 3 μm or less, for example, 2.3 μm .

An upper layer out of the at least two layers overlapping each other on the TFT T to shield the semiconductor layer

108 has a fourth thickness **14**. The fourth thickness **14** is about 2 μm or less, for example, 1.4 μm .

As described above, the column spacer **150** and the white pattern **124** are formed in the same process i.e., the same mask process, thus a number of mask processes can be reduced and productivity can be improved.

Further, because the column spacer **150** may be made of the same material as the white pattern **124**, which is relatively inexpensive, production cost can also be reduced compared with the LCD according to the related art, which uses an expensive black column spacer.

A method of manufacturing a COT-type LCD according to an embodiment of the present invention is now described with reference to FIGS. 2A to 2G.

FIGS. 2A to 2G are cross-sectional views illustrating a method of manufacturing a COT-type LCD according to an embodiment of the present invention. For brevity, the green color filter formed in the same manner as the blue and red color filters is omitted.

Referring to FIG. 2A, the TFT T, the gate line, and the data line **116** are formed on the first substrate **100**. The TFT T includes the gate electrode **102**, the semiconductor layer **108**, and the source and drain electrodes **112** and **114**.

The gate electrode **102** and the gate line may be formed by depositing a conductive material having low resistance and being opaque such as Al, Al alloy, W, Cu, Ni, Cr, Mo, Ti, Pt or Ta, or a transparent conductive material such as ITO or IZO on the first substrate **100** and then patterning the deposited material in a mask process.

Then, the gate insulating layer **106** is formed on the gate electrode **102** and the gate line. The semiconductor layer **108**, and the source and drain electrodes **112** and **114** are formed on the gate insulating layer **106**. The data line **116** is formed in the same process of forming the source and drain electrodes **112** and **114**.

The source and drain electrodes **112** and **114**, and the data line **116** may be formed by depositing a metal such as Al, Cu, Ni, Cr, Ti, Pt, Ta, Ti alloy, Mo or Mo alloy on the first substrate **100** and patterning the deposited material in a mask process.

The passivation layer **118** is formed on the first substrate **100** having the source and drain electrodes **112** and **114**.

Referring to FIG. 2B, the blue, red and green color filters **122a**, **122b** and **122c** are then formed.

The blue, red and green color filters **122a**, **122b** and **122c** are formed in the respective mask processes. The blue, red and green color filters **122a**, **122b** and **122c** each have a thickness of about 3 μm or less. For example, the thickness of each of the blue, red and green color filters **122a**, **122b** and **122c** is about 2.3 μm .

At least two color filters, for example, the blue and red color filters **122a** and **122b** overlap each other on the TFT T, and the upper color filter of the at least two color filters, for example, the blue color filter **122a** extending over the TFT T of the neighboring pixel region P has about 2 μm or less, for example, about 1.4 μm .

Although not shown in the drawings, one of the blue, red and green color filters **122a**, **122b** and **122c** overlaps the other one of the blue, red and green color filters **122a**, **122b** and **122c** on the TFT T of the neighboring pixel region P.

Referring to FIG. 2C, the planarization layer **126** is then formed on the blue, red and green color filters **122a**, **122b** and **122c**.

The planarization layer **126** and the passivation layer **118** are patterned in a mask process to form a drain contact hole **114a** exposing the drain electrode **114**, and to form a white

pattern hole **126a** in the white pixel region. The white pattern hole **126a** in the white pixel region is later filled with the white pattern **124**.

Referring to FIG. 2D, an organic material, for example, an acryl resin is then coated on the first substrate **100** having the planarization layer **126**.

In this case, the organic material **140** is in a liquid state so that it flows from a higher level to a lower level. Accordingly, the organic material **140** is coated all over the first substrate **100** filling the drain contact hole **114a** and the white pattern hole **126a**.

The organic material **140** is photosensitive. Accordingly, a photo mask **145** is positioned over the first substrate **100**, and then a light exposure process and a developing process for the organic material **140** are conducted. The photo mask **145** includes a transmissive portion TA, a semi-transmissive portion SA, and a blocking portion BA. The transmissive portion TA corresponds to the blue, red and green pixel regions, the semi-transmissive portion SA corresponds to the white pattern hole **126a**, and the blocking portion corresponds to the TFT T.

Referring to FIG. 2E, the organic material **140** is then patterned to form the column spacer **150** and the white pattern **124** simultaneously. The column spacer **150** is formed over the TFT T, and the white pattern **124** is formed in the white pattern hole **126a**.

The column spacer **150** has a thickness of about 3 μm or less, for example, about 2.4 μm . The white pattern **124** has a thickness of about 4 μm or less, for example, 3.7 μm .

Because the column spacer **150** and the white pattern **124** are formed in the same mask process, a number of mask processes can be reduced, and thus productivity can be improved.

Referring to FIG. 2F, the pixel electrode **130** is formed in each pixel region P and on the planarization layer **126** and the white pattern **124**. The pixel electrode **130** is electrically connected to the drain electrode **114** through the drain contact hole **114a**.

Referring to FIG. 2G, the second substrate **190** having a common electrode **197** thereon is then attached to the first substrate **100**.

The liquid crystal layer **160** is provided between the first and second substrates **100** and **190**.

Through the above-described processes, the COT-type LCD is manufactured.

In the above COT-type LCD, at least two of the blue, red and green color filters **122a**, **122b** and **122c** are stacked and overlap each other on the TFT T, and thus functions as a black matrix to shield the semiconductor layer from light.

Further, the column spacer **150** and the white pattern **124** are formed in the same mask process. Accordingly, a number of mask processes can be reduced, and thus production cost can be reduced and productivity can be improved.

It will be apparent to those skilled in the art that various modifications and variation can be made in the present invention without departing from the spirit or scope of the invention. Thus, it is intended that the present invention cover the modifications and variations of this invention provided they come within the scope of the appended claims and their equivalents.

What is claimed is:

1. A color filter on transistor (COT) type liquid crystal display device, comprising:

red, green, blue and white pixels on a substrate;

red, green and blue color filters in the red, green and blue pixels, respectively, and a white pattern in the white pixel, wherein at least two of the red, green and blue

color filters are stacked together in a black matrix region to serve as a black matrix and to cover and shield from light a portion of a semiconductor layer located between source and drain electrodes of a thin film transistor in one of the red, green and blue pixels;

a pixel electrode that is on the white pattern in the white pixel and is connected to the drain electrode through a drain contact hole in the white pixel;

a planarization layer on the red, green and blue color filters; and

a column spacer on the planarization layer in a region where the at least two of the red, green and blue color filters are stacked together to cover the semiconductor layer between the source and drain electrodes, and

wherein the column spacer and the white pattern are made of a same transparent material, and a thickness of the white pattern is substantially equal to a total thickness of: (1) the planarization layer and the red, green or blue color filter in the respective red, green or blue pixel, and (2) the planarization layer and the at least two of the red, green and blue color filters stacked together in the black matrix region,

wherein the white pattern and the planarization layer are distinct layers,

wherein the column spacer has a first thickness and the white pattern has a second thickness greater than the first thickness, and

wherein the pixel electrode contacts a side surface, located at a side of the drain contact hole, of the white pattern, and contacts a side surface, located at an opposing side of the drain contact hole, of one of the red, green and blue color filters that neighbors with the white pattern and extends into the white pixel.

2. The device of claim 1, wherein the column spacer has a first thickness of about 3 μm or less, and the white pattern has a second thickness of about 4 μm or less.

3. The device of claim 1, wherein each of the red, green and blue color filters has a third thickness of about 3 μm or less, and wherein an upper layer of the at least two of the red, green and blue color filters has a fourth thickness of about 2 μm or less.

4. The device of claim 1, wherein the column spacer and the white pattern are made of an organic material.

5. The device of claim 1, wherein a top surface of the planarization layer on each of the red, green and blue color filters is substantially equal to that of the planarization layer in an overlap region where the at least two of the red, green and blue color filters are stacked together to cover the semiconductor layer between the source and drain electrodes.

6. The device of claim 1, wherein the at least two of the red, green and blue color filters stacked together in the black matrix region to serve as a black matrix comprise end portions of the at least two of the red, green and blue color filters.

7. A method of manufacturing a color filter on transistor (COT) type liquid crystal display device, comprising:

forming a thin film transistor on a first substrate, the thin film transistor including a gate electrode, an active layer and source and drain electrodes;

forming a passivation layer on the thin film transistor;

forming red, green and blue color filters on the passivation layer in respective pixel regions, wherein at least two of the red, green and blue color filters are stacked together in a black matrix region to serve as a black matrix and to cover and shield from light a portion of the active layer located between the source and drain electrodes;

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forming a planarization layer on the red, green and blue color filters so that a top surface of the planarization layer on each of the red, green and blue color filters is substantially equal to that of the planarization layer in an overlap region where the at least two of the red, green and blue color filters are stacked together to cover the semiconductor layer between the source and drain electrodes;

forming a white pattern hole in the planarization layer; forming a transparent organic material over the substrate having the planarization layer including the white pattern hole;

forming a column spacer in the overlap region and a white pattern by patterning the transparent organic material using a blocking portion of a mask and a semi-transparent portion of the mask for the column spacer and the white pattern, respectively, wherein a thickness of the white pattern is substantially equal to a total thickness of: (1) the planarization layer and the red, green or blue color filter in the respective red, green or blue pixel, and (2) the planarization layer and the at least two of the red, green and blue color filters stacked together in the black matrix region; and

forming a pixel electrode electrically connected to the drain electrode,

wherein the white pattern and the planarization layer are distinct layers,

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wherein the pixel electrode on the white pattern in the white pixel is connected to the drain electrode through a drain contact hole in the white pixel,

wherein the pixel electrode in the white pixel contacts a side surface, located at a side of the drain contact hole, of the white pattern, and contacts a side surface, located at an opposing side of the drain contact hole, of one of the red, green and blue color filters that neighbors with the white pattern and extends into the white pixel.

8. The method of claim 7, wherein the column spacer has a first thickness and the white pattern has a second thickness greater than the first thickness.

9. The method of claim 8, wherein the first thickness is about 3 μm or less, and the second thickness is about 4 μm or less.

10. The method of claim 7, wherein each of the red, green and blue color filters has a third thickness of about 3 μm or less.

11. The method of claim 7, wherein the organic material is photosensitive, and the column spacer and the white pattern are simultaneously formed by irradiating a light onto the organic material.

12. The method of claim 7, wherein the at least two of the red, green and blue color filters stacked together in the black matrix region to serve as a black matrix comprise end portions of the at least two of the red, green and blue color filters.

* * * * *

专利名称(译)	COT型液晶显示装置		
公开(公告)号	US9977280	公开(公告)日	2018-05-22
申请号	US14/540125	申请日	2014-11-13
[标]申请(专利权)人(译)	乐金显示有限公司		
申请(专利权)人(译)	LG DISPLAY CO. , LTD.		
当前申请(专利权)人(译)	LG DISPLAY CO. , LTD.		
[标]发明人	KIM TAE YOUNG BYUN WOO JUNG LEE SANG HO		
发明人	KIM, TAE-YOUNG BYUN, WOO-JUNG LEE, SANG-HO		
IPC分类号	G02F1/1335 G02F1/1339 G02F1/1362		
CPC分类号	G02F1/133514 G02F1/13394 G02F2201/48 G02F2001/136222 G02F1/1333 G02F2001/133357 G02F2001/13398		
代理机构(译)	DENTONS美国律师事务所		
助理审查员(译)	CHUNG , DAVID		
优先权	1020130168767 2013-12-31 KR		
其他公开文献	US20150185551A1		
外部链接	Espacenet USPTO		

摘要(译)

公开了一种在衬底上可以包括红色，绿色，蓝色和白色像素的晶体管（COT）型液晶显示装置上的滤色器；红色，绿色和蓝色滤色器分别为红色绿色和蓝色像素，白色像素中为白色图案；红色，绿色和蓝色滤色器上的平面化层；以及平坦化层上的柱状间隔物，其中柱状间隔物和白色图案由基本相同的材料制成。

